Proposal for in situ Enhancem ent of Electron Spin Polarization in Sem iconductors.

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An extension of the original Overhauser e ect to a more general nonequilibrium state was proposed by G. Feher, and demonstrated by C lark and Feher some forty years ago. It is suggested here that it might be possible to produce excess electron spin polarization by allowing the role of the nuclei to be played by other magnetic entities, such as param agnetic impurities or adjacent magnetically ordered structures.

I. Background: Plans to utilize the spin degree of freedom of electrons (rather than only their charge) in the construction of sem iconductor devices depend on the creation of a degree of spin polarization well in excess of the very small net alignment available in ordinary magnetice elds, especially at room tem perature. An appealing way to achieve large polarization is to inject electrons from the majority Ferm isea in a ferror agnetic metal into the sem iconductor. G iant m agnetoresistance heterostructures, involving in jection of the polarized electrons into, and transmission through, a nonm agnetic m etal, raise hopes that such in jection, and subsequent transport, will be possible in sem iconductors also. So far, only a few successes have been claim ed. These either involve cryogenic tem peratures, or else use sem iconducting material not favored in applications<sup>1</sup>. Also, in a certain sem iconductor, anom alously high q values due to band structure e ects have been reported<sup>2</sup>; obviating the need for polarized in jection, but, again, very low tem peratures are needed. Som e success has been reported involving optical methods; and probably reection (rather than injection) from , a ferrom agnet.

Here, a method is proposed that avoids the need for injection or relection altogether, and should function at room temperature. It is based on a kind of inversion of a generalized O verhauser elect proposed in 1959 by G. Feher<sup>4</sup>; and subsequently realized experimentally by W.G.Clark and G.Feher<sup>5</sup>: The original O verhauser elect described greatly enhanced nuclear spin polarization resulting from strong excitation of the paramagnetic resonance of electrons in hyper ne interaction with the nuclei. The major insight achieved by Feher<sup>4</sup> was that the crucial feature of the O verhauser

e ect was not the microwave excitation of the electrons, but simply their non-equilibrium distribution, no matter how produced. In the Clark-Feher experiment, the electrons are thrown out of equilibrium by an electric eld applied to the semiconductor, (indium antimonide), heating the electrons to a temperature  $T_H$ , say. The hyper ne coupling of such a 'hot' electrons to the  $In^{115}$  nuclei causes a simultaneous spin ip of the electronic and nuclear spins. Single spin ips of the electron by spin-orbit coupling to the lattice also occur, but may be ignored initially. Single spin ips of the nuclei lead to very long spin lifetim es and may be ignored altogether. Let  $A_+$ ; A denote the concentrations of upspin and downspin hot electrons, and  $B_+$ ; B the number of upspin and downspin nuclei respectively. Then (since single spin

ip processes are ignored for now ), the master equation for  $A_{\!\scriptscriptstyle +}\,$  reads, in the steady state

$$W_{+} + A_{+} B_{+} W_{+} + A_{+} B_{-} = 0$$
 (2)

where W  $_{+)+}$  is the rate of simultaneous spin reversal of electron and nucleus, the form er from down to up, the latter from up to down, and similarly for W  $_{+)+}$ : Since this mutual spin ip process, which does not conserve energy, is powered by the hot electrons, the ratio of the two W 's has a value appropriate to detailed balance at tem perature  $T_{\rm H}$ :

$$\frac{W_{+} + K_{+}}{W_{+} + K_{+}} = \exp \frac{2(K_{A} + K_{B})H}{K_{b}T_{H}}$$
(3)

where  $_{A}$ ;  $_{B}$  are the magnetic moments of the electrons and nuclei, and H the applied magnetic eld. In this open, non-equilibrium system, the occupation numbers A; B will be given by Boltzmann factors  $_{A}^{H} = k_{b}T_{A}$ ;  $e^{_{B}H} = k_{b}T_{B}$  with their own temperatures  $T_{A}$  and  $T_{B}$ : Thus from equations (1) and (2),

$$\frac{A_{+}}{A} \frac{B_{+}}{B_{+}} = e^{2_{A}H = k_{b}T_{A}} e^{2_{B}H = k_{b}T_{B}}$$

$$= e^{\frac{2(A_{B})H}{k_{b}T_{H}}}$$
(4)

whence

$$\frac{B}{T_{B}} = \frac{A}{T_{A}} \qquad \frac{A}{T_{H}} \qquad (5)$$

This shows that for them all energies of the hot electron far in excess of the magnetic energies,  $\frac{A_{iB}}{k_{b}T_{A_{iB}}}$ ; the quantity determining the extent of nuclear polarization approaches  $\frac{A_{iB}}{k_{b}T_{A}}$ ; which determines the much bigger electronic

polarization. In other words,  $\frac{B_+}{B}$  !  $\frac{A_+}{A}$  as  $T_H$  ! 1 : (U sually, this result is written as a greatly reduced e ective nuclear temperature  $T_B = -\frac{B}{A} T_A$ ): Note that this assumes that the electron variables are 'robust', with  $T_A$  rigidly

xed. Equation (4) could equally well slave T<sub>A</sub> to a rigidly xed nuclear temperature. This di culty is resolved by taking single ip processes into account (see next section)

<u>II. This Proposal</u>: The essence of this proposal is to let the role of the nucleibe assumed by magnetic entities (for example paramagnetic in purities with electronic magnetic moment  $_{A}$ . Then  $_{A}$  !  $_{B}$   $\frac{T_{A}}{T_{B}}$  as  $T_{H}$  ! 1 : In as much as in such a system  $\frac{T_{A}}{T_{B}}$  might be of order one, the electrons will have acquired the magnetic moment of the impurity.

W hen single ip processes of the electrons and of the 'in purities' are not neglected, it is found that this result retains its validity if a certain inequality is satistical. Note that the total concentrations of the A and B species scale out of equation (1) which is how ogeneous of degree 2. Inclusion of single ip processes spoils the how ogeneity and results in a concentration dependence. Writing  $A_{+} = A \cos^{2}_{A}$ ;  $A = A \sin^{2}_{A}$ ;  $B_{+} = B \cos^{2}_{B}$ ;  $B = B \sin^{2}_{B}$ , with total concentrations A; B; the steady state m aster equations for  $A_{+}$ ;  $B_{+}$  now read

$$U + Aw_{+!}^{A} \cos^{2} A W_{!+}^{A} \sin^{2} A = 0$$
(6)  
$$U + Bw_{+!}^{B} \cos^{2} B W_{!+}^{B} \sin^{2} B = 0$$

where

$$U = AB W_{+} + \cos^{2} A \sin^{2} B W_{+} + \sin^{2} A \cos^{2} B$$
(7)

Here,  $w_{++}^{A} = w^{A} \exp(A_{A} H = k_{b}T_{A})$ ;  $w_{++}^{A} = w^{A} \exp(A_{A} H = k_{b}T_{B})$  are the single ip rates for the electrons, and similarly for the 'in purities'. These ips are powered by lattice vibrations via spin-orbit coupling, so that both  $T_{A} \& T_{B}$  are presumably of order of the lattice temperature. A lineage equations (5) and (6) can be reduced to a single quadratic, (for  $\cos 2_{A}$ ; for example), the coecients are very involved. However, there appears to be one particularly simple solution for which A = B = 1 if  $U \in O$ ; this solution, according to equations (5), must satisfy

$$Aw_{+!}^{A} \cos^{2} Aw_{!+}^{A} \sin^{2} = (Bw_{+!}^{B} \cos^{2} Bw_{!+}^{B} \sin^{2})$$
 (8)

or

$$\cot^{2} = \frac{A w^{A}_{!} + B w^{B}_{!}}{A w^{A}_{+!} + B w^{B}_{+!}}$$

$$= \frac{1 + \frac{B w^{B}}{A w^{A}} e^{(B = T_{B} A = T_{A})H = k_{D}}}{1 + \frac{B w^{B}}{A w^{A}} e^{(B = T_{B} A = T_{A})H = k_{D}}}$$
(10)

This is consistent with the earlier, concentration independent result  $\cot^2 = e^{2_B = k_b T_B}$  for very large  $T_H$ , provided  $\frac{B w^B}{A w^A} e^{(B_B = T_B) A_B = T_A)H = k_b}$  is much greater than 1, and  $A = T_A << B = T_B$ . (Note that, if  $T_H$  were allowed to go to in nity, i.e. U ! 0; at the beginning of the calculation, this solution would fail.). An improved solution may be obtained by writing A = A + A, B = A + B in equation (5), in the denition (6) for U; and expanding to rest order in the 's, resulting in two rest order linear simultaneous equations for A and B.

<u>III. Possible Implem entation</u>. In the above, the 'impurity' was characterized as a simple magnetic moment  $_{\rm B}$  and its Zeem ann energy in a magnetic

eld. To signi cantly enhance the electron spin polarization, the implanted in purity must have a large spin and/or an anom alously large q factor. In a magnetic eld of 1 T, the electron polarization  $(A_{+}=A_{-})$  1 in the absence of the impurity would only be 0.6% at room temperature. If the implant has a spin of 2, this gure would be increased to about 2.4% . (Although the analysis in section  $\Pi$  was phrased in terms of an impurity with spin 1/2, the results are easily shown to hold for larger spins also, as long as the levels are equispaced). A further increase could come if spin-orbit coupling to the crystal lattice results in a large axial anisotropy energy for that implanted ion. This might conceivably amount to an additional e ective eld of one Tessler, giving 4.8% excess polarization. However, much better results can be obtained if the 'im purity' is replaced by be any magnetic structure with a lowest magnetic excitation energy far in excess of any readily accessible Zeem ann energy. O ne prom ising case would be a pair of ions with spins coupled by anisotropic exchange energy (isotropic exchange does not work, since it commutes with the coupling s  $S_1 + S_2$  to the conduction electron spin). For example, an exchange  $J(S_{1x}S_{sx} + S_{1y}S_{sy})$  would give an energy gap of order J; commonly of order of several hundred cm<sup>1</sup>: If <sub>B</sub>H in the foregoing results is replaced by this energy, it would give alm ost 100% electron spin polarization. (However, there may be a serious problem here: energy conservation obviously requires that the electrons are hot enough to deliver

this kind of energy in the mutual spin ip process. A ssum ing a mobility of 1000cm /sec/volt/cm, with the translational velocity acquired from the electric eld totally random ized, an energy gap of 100 cm <sup>1</sup>would require an electric eld of about  $10^{\circ}$  volts/cm. C lark and Feher in their experiment noted that a eld of only 150 volts/cm already led to breakdown, probably by in pact ionization of donor ions.) Finally, in plantation m ay be avoided altogether by building a heterostructure consisting of a thin sem iconducting

In sandwiched between two antiferrom agnetic insulators. If the anisotropy and exchange energies of the latter are J and K respectively, their lowest excitation energy is of order JK; again far above Zeem ann energy in a commonly used magnetic eld. A full analysis requires allowing for position dependence of A and B and excitation of the antiferrom agnetic in a long the structure. This will be presented in a future calculation.

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